

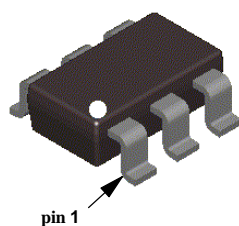
FDC6323L Integrated Load Switch

General Description

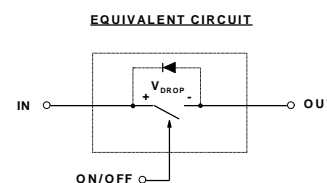
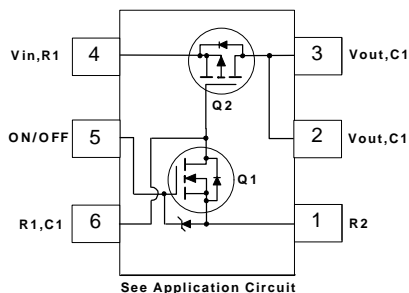
These Integrated Load Switches are produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage high side load switch application where low conduction loss and ease of driving are needed.

Features

- $V_{\text{DROP}}=0.2\text{V} @ V_{\text{IN}}=5\text{V}, I_{\text{L}}=1\text{A}, V_{\text{ON/OFF}}= 1.5\text{V to } 8\text{V}$
 $V_{\text{DROP}}=0.3\text{V} @ V_{\text{IN}}=3.3\text{V}, I_{\text{L}}=1\text{A}, V_{\text{ON/OFF}}= 1.5\text{V to } 8\text{V}.$
- High density cell design for extremely low on-resistance.
- $V_{\text{ON/OFF}}$ Zener protection for ESD ruggedness. >6KV Human Body Model.
- SuperSOT™-6 package design using copper lead frame for superior thermal and electrical capabilities.



SuperSOT™-6



Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	FDC6323L	Units
V_{IN}	Input Voltage Range	3 - 8	V
$V_{\text{ON/OFF}}$	On/Off Voltage Range	1.5 - 8	V
I_{L}	Load Current @ $V_{\text{DROP}}=0.5\text{V}$ - Continuous (Note 1)	1.5	A
	- Pulsed (Note 1 & 3)	2.5	
P_{D}	Maximum Power Dissipation (Note 2a)	0.7	W
$T_{\text{J}}, T_{\text{STG}}$	Operating and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
ESD	Electrostatic Discharge Rating MIL-STD-883D Human Body Model (100pf/1500Ohm)	6	kV

THERMAL CHARACTERISTICS

$R_{\theta\text{JA}}$	Thermal Resistance, Junction-to-Ambient (Note 2a)	180	$^\circ\text{C/W}$
$R_{\theta\text{JC}}$	Thermal Resistance, Junction-to-Case (Note 2)	60	$^\circ\text{C/W}$

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
I _{FL}	Forward Leakage Current	V _{IN} = 8 V, V _{ON/OFF} = 0 V			1	μA
I _{RL}	Reverse Leakage Current	V _{IN} = -8 V, V _{ON/OFF} = 0 V			-1	μA
ON CHARACTERISTICS (Note 3)						
V _{IN}	Input Voltage		3		8	V
V _{ON/OFF}	On/Off Voltage		1.5		8	V
V _{DROP}	Conduction Voltage Drop @ 1A	V _{IN} = 5 V, V _{ON/OFF} = 3.3 V		0.145	0.2	V
		V _{IN} = 3.3 V, V _{ON/OFF} = 3.3 V		0.178	0.3	
I _L	Load Current	V _{DROP} = 0.2 V, V _{IN} = 5 V, V _{ON/OFF} = 3.3 V	1			A
		V _{DROP} = 0.3 V, V _{IN} = 3.3 V, V _{ON/OFF} = 3.3 V	1			

Notes:

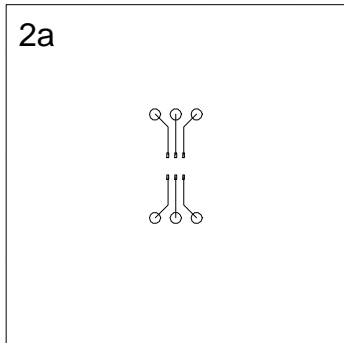
1. V_{IN}=8V, V_{ON/OFF}=8V, V_{DROP}=0.5V, T_A=25°C

2. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design while R_{θCA} is determined by the user's board design.

$$P_D(t) = \frac{T_J - T_A}{R_{\theta J A}(t)} = \frac{T_J - T_A}{R_{\theta J C} + R_{\theta C A}(t)} = I_D^2(t) \times R_{DS(ON)} @ T_J$$

Typical R_{θJA} for single device operation using the board layouts shown below on FR-4 PCB in a still air environment:

a. 180°C/W when mounted on a 2oz minimum copper pad.



Scale 1 : 1 on letter size paper

3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

Typical Electrical Characteristics ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

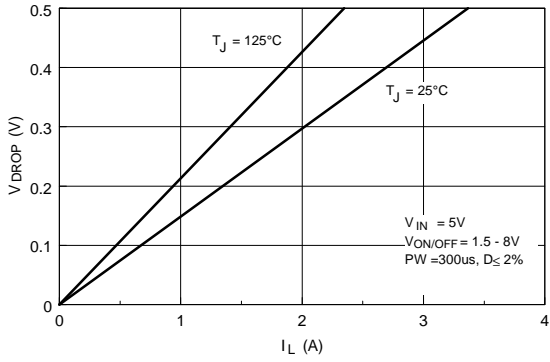


Figure 1. V_{DROP} Versus I_L at $V_{IN} = 5\text{V}$.

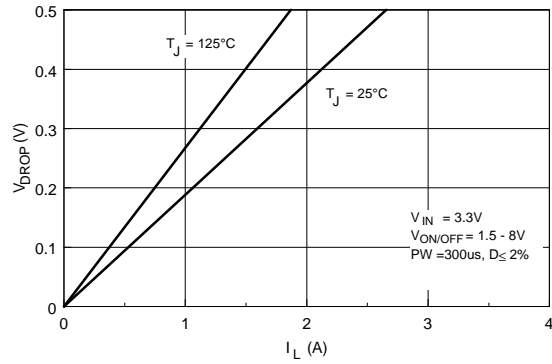


Figure 2. V_{DROP} Versus I_L at $V_{IN} = 3.3\text{V}$.

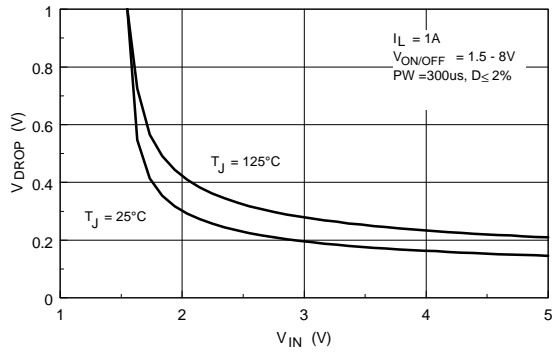


Figure 3. V_{DROP} Versus V_{IN} at $I_L = 1\text{A}$.

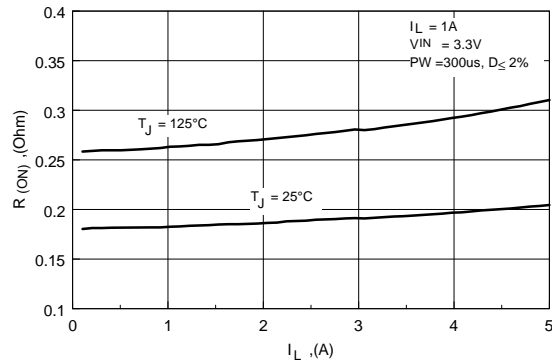


Figure 4. R_{ON} Versus I_L at $V_{IN} = 3.3\text{V}$.

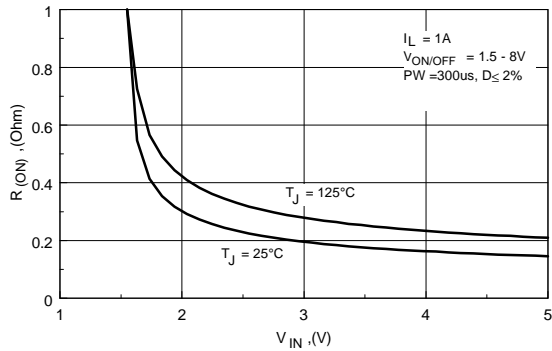


Figure 5. On Resistance Variation with Input Voltage.

Typical Electrical Characteristics ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

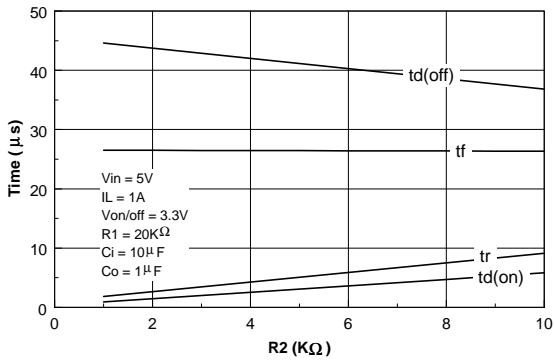


Figure 6. Switching Variation with R2 at Vin = 5V and R1 = 20KOhm.

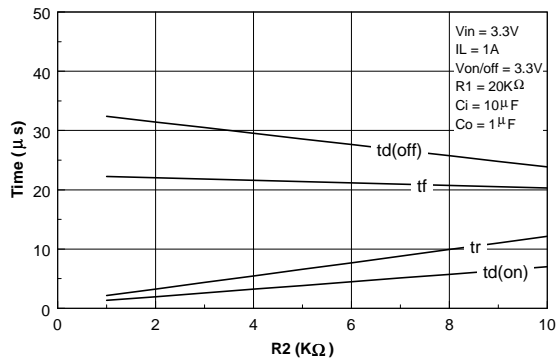


Figure 7. Switching Variation with R2 at Vin = 3.3V and R1 = 20KOhm.

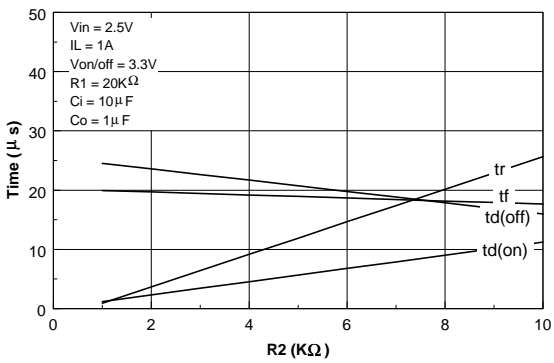


Figure 8. Switching Variation with R2 at Vin = 2.5V and R1 = 20KOhm.

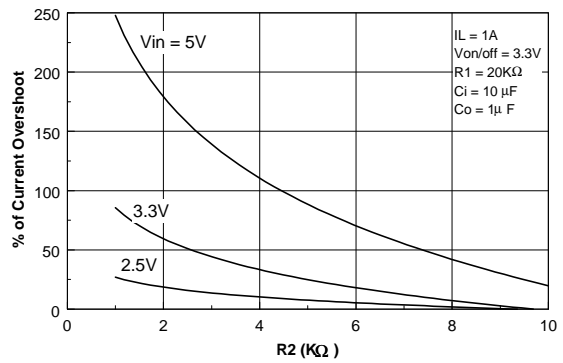


Figure 9. % of Current Overshoot Variation with Vin and R2.

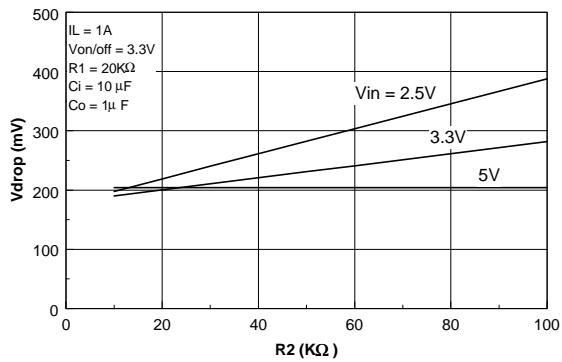


Figure 10. Vdrop Variation with Vin and R2.

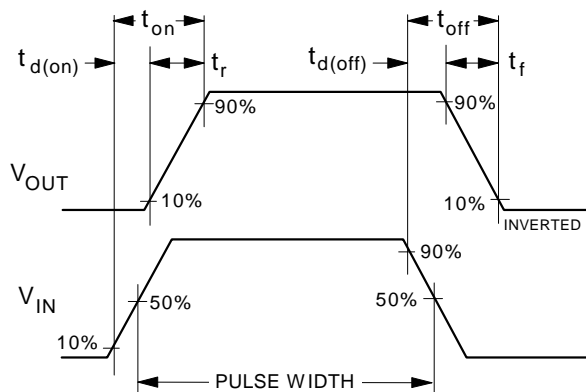


Figure 11. Switching Waveforms.

Typical Electrical Characteristics ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

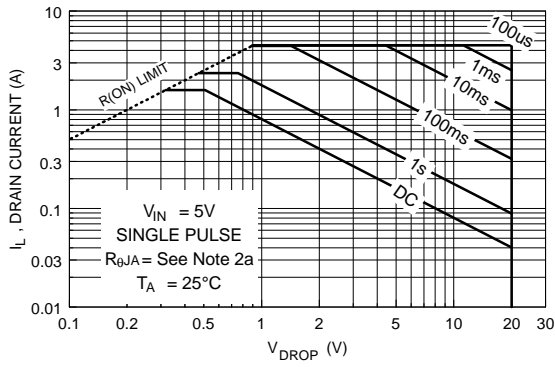


Figure 12. Safe Operating Area.

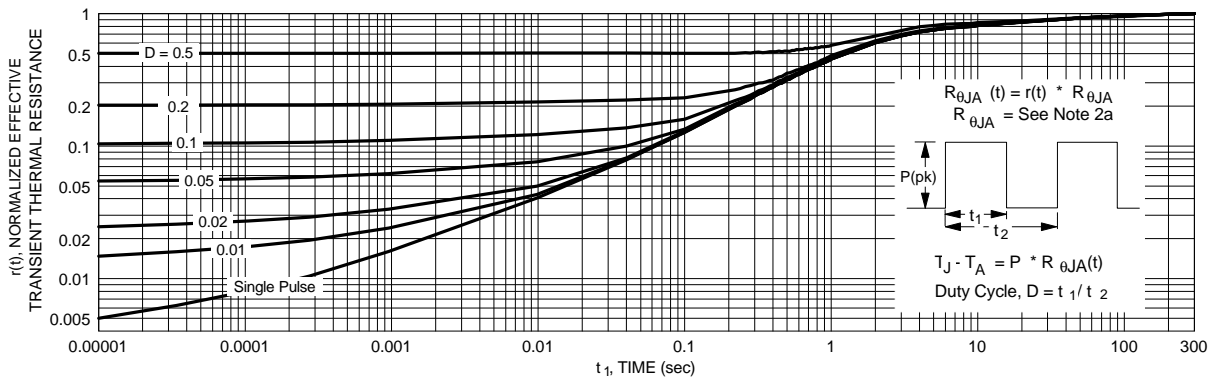
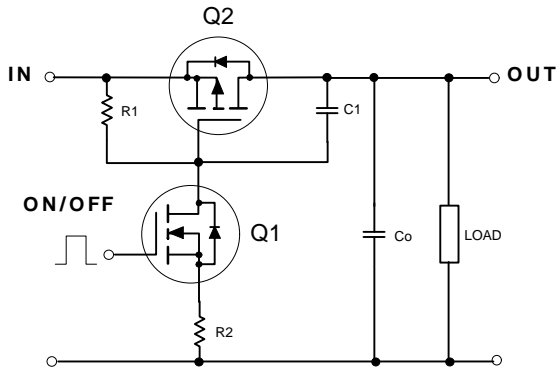


Figure 13. Transient Thermal Response Curve.

Note: Thermal characterization performed on the conditions described in Note 2a. Transient thermal response will change depends on the circuit board design.

FDC6323L Load Switch Application

APPLICATION CIRCUIT



General Description

This device is particularly suited for compact computer peripheral switching applications where 8V input and 1A output current capability are needed. This load switch integrates a small N-Channel Power MOSFET (Q1) which drives a large P-Channel Power MOSFET (Q2) in one tiny SuperSOT™-6 package.

A load switch is usually configured for high side switching so that the load can be isolated from the active power source. A P-Channel Power MOSFET, because it does not require its drive voltage above the input voltage, is usually more cost effective than using an N-Channel device in this particular application. A large P-Channel Power MOSFET minimizes voltage drop. By using a small N-Channel device the driving stage is simplified.

Component Values

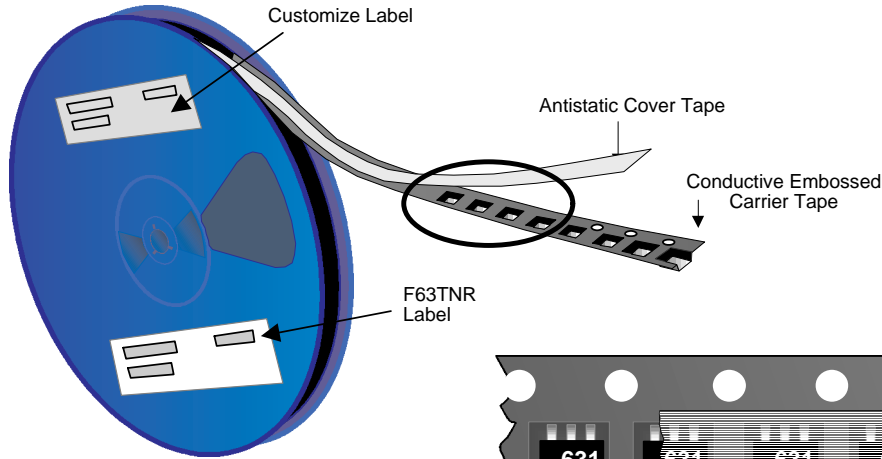
R1	Typical 10k - 1MΩ
R2	Typical 0 - 100kΩ (optional)
C1	Typical 1000pF (optional)

Design Notes

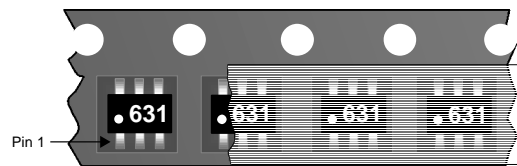
- R1 is needed to turn off Q2.
- R2 can be used to soft start the switch in case the output capacitance Co is small.
- R2 should be at least 10 times smaller than R1 to guarantee Q1 turns on.
- By using R1 and R2 a certain amount of current is lost from the input. This bias current loss is given by the equation
$$I_{BIAS_LOSS} = \frac{V_{in}}{R1 + R2}$$
when the switch is ON. I_{BIAS_LOSS} can be minimized by selecting a large value for R1.
- R2 and C_{RSS} of Q2 make ramp for slow turn on. If excessive overshoot current occurs due to fast turn on, additional capacitance C1 can be added externally to slow down the turn on.

SuperSOT™-6 Tape and Reel Data and Package Dimensions

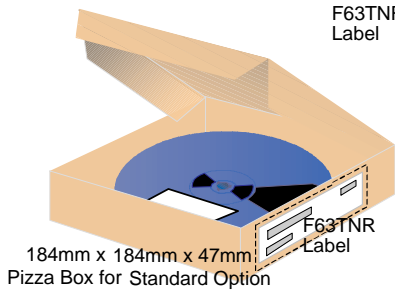
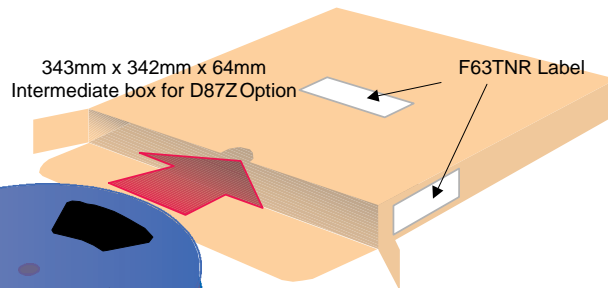
SSOT-6 Packaging
Configuration: Figure 1.0



SSOT-6 Packaging Information		
Packaging Option	Standard (no flow code)	D87Z
Packaging type	TNR	TNR
Qty per Reel/Tube/Bag	3,000	10,000
Reel Size	7" Dia	13"
Box Dimension (mm)	184x187x47	343x343x64
Max qty per Box	9,000	20,000
Weight per unit (gm)	0.0158	0.0158
Weight per Reel (kg)	0.1440	0.4700
Note/Comments		



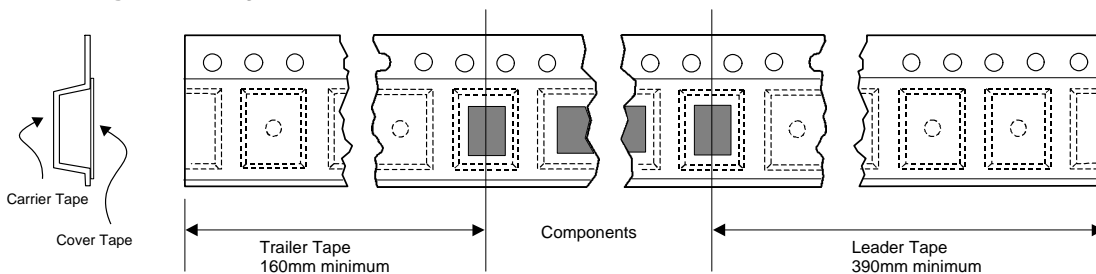
SSOT-6 Unit Orientation



F63TNR Label sample

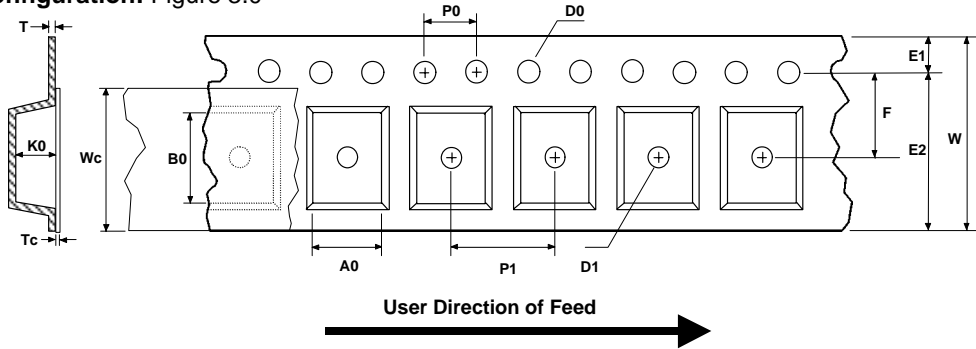


SSOT-6 Tape Leader Trailer Configuration: Figure 2.0



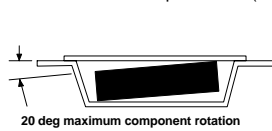
SuperSOT™-6 Tape and Reel Data and Package Dimensions, continued

SSOT-6 Embossed Carrier Tape Configuration: Figure 3.0

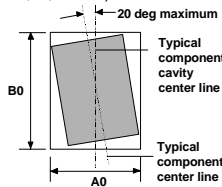


Dimensions are in millimeter														
Pkg type	A0	B0	W	D0	D1	E1	E2	F	P1	P0	K0	T	Wc	Tc
SSOT-6 (8mm)	3.23 +/-0.10	3.18 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.00 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.37 +/-0.10	0.255 +/-0.150	5.2 +/-0.3	0.06 +/-0.02

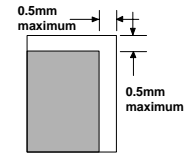
Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation

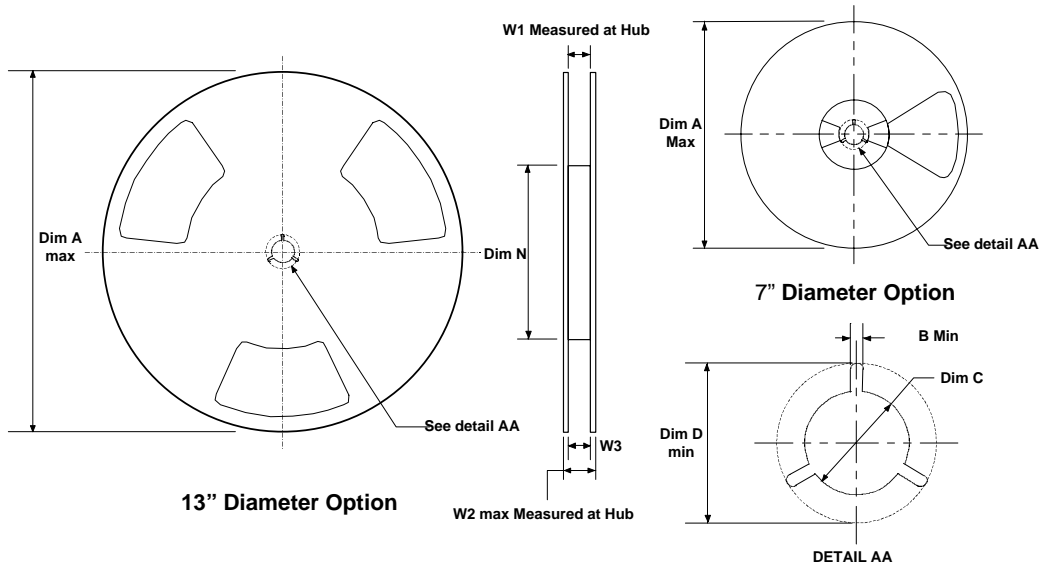


Sketch B (Top View)
Component Rotation



Sketch C (Top View)
Component lateral movement

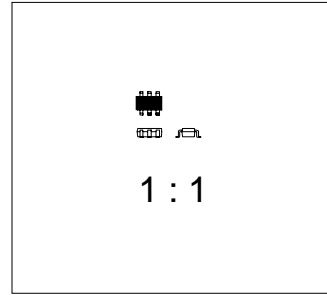
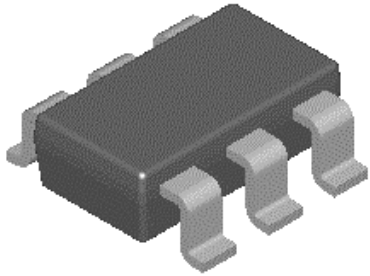
SSOT-6 Reel Configuration: Figure 4.0



Dimensions are in inches and millimeters									
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9

SuperSOT™-6 Tape and Reel Data and Package Dimensions, continued

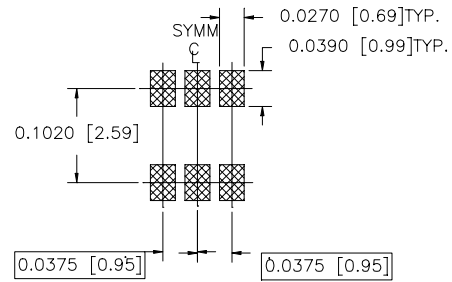
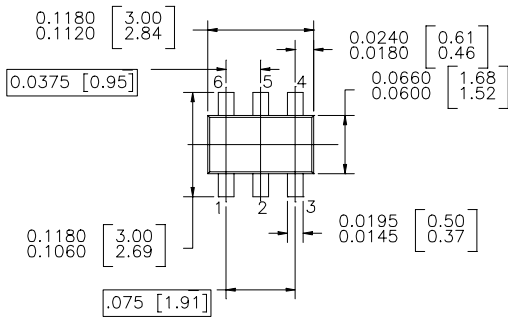
SuperSOT™-6 (FS PKG Code 31, 33)



Scale 1:1 on letter size paper

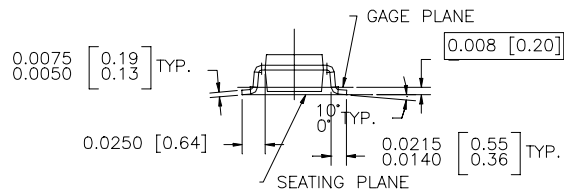
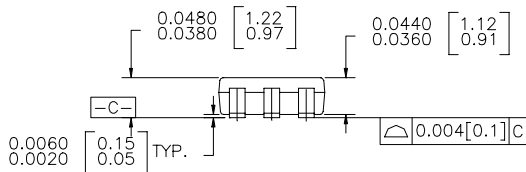
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.0158



LAND PATTERN RECOMMENDATION

CONTROLLING DIMENSION IS INCH
VALUES IN [] ARE MILLIMETERS



SUPER SOT 6 LEADS

NOTES : UNLESS OTHERWISE SPECIFIED

1.0 STANDARD LEAD FINISH : 150 MICRONS 93.81 MICROMETERS)
MINIMUM TIN / LEAD (SOLDER) ON COPPER.

2.0 NO JEDEC REGISTRATION AS OF JULY 1996

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	ISOPLANAR™
CoolFET™	MICROWIRE™
CROSSVOLT™	POP™
E ² CMOS™	PowerTrench™
FACT™	QS™
FACT Quiet Series™	Quiet Series™
FAST®	SuperSOT™-3
FASTr™	SuperSOT™-6
GTO™	SuperSOT™-8
HiSeC™	TinyLogic™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.